

M1MA151WK, M1MA152WK

Common Cathode Silicon Dual Switching Diodes

These Common Cathode Silicon Epitaxial Planar Dual Diodes are designed for use in ultra high speed switching applications. These devices are housed in the SC-59 package which is designed for low power surface mount applications.

Features

- Fast t_{rr} , < 3.0 ns
- Low C_D , < 2.0 pF
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

| Rating | Symbol | Value | Unit |
|--|-----------------------|------------|------|
| Reverse Voltage M1MA151WK M1MA152WK | V_R | 40 80 | Vdc |
| Peak Reverse Voltage M1MA151WK M1MA152WK | V_{RM} | 40 80 | Vdc |
| Forward Current Single Dual | I_F | 100 150 | mAdc |
| Peak Forward Current Single Dual | I_{FM} | 225 340 | mAdc |
| Peak Forward Surge Current Single Dual | I_{FSM} (Note 1) | 500 750 | mAdc |

THERMAL CHARACTERISTICS

| Rating | Symbol | Max | Unit |
|----------------------|-----------|-------------|------------------|
| Power Dissipation | P_D | 200 | mW |
| Junction Temperature | T_J | 150 | $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. $t = 1$ sec



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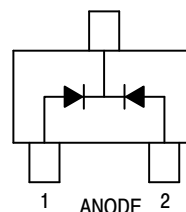
www.onsemi.com

**SC-59 PACKAGE SINGLE SILICON
SWITCHING DIODES 40 V/80 V 100 mA
SURFACE MOUNT**

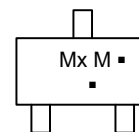


**SC-59
CASE 318D
STYLE 3**

3 CATHODE



MARKING DIAGRAM



Mx = Device Code
x = T for 151
U for 152
M = Date Code*
▪ = Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

| Device | Package | Shipping† |
|-----------------|--------------------|------------------------|
| M1MA151WKT1G | SC-59 (Pb-Free) | 3,000 / Tape & Reel |
| SM1MA151WKT1G | SC-59 (Pb-Free) | 3,000 / Tape & Reel |
| M1MA152WKT1G | SC-59 (Pb-Free) | 3,000 / Tape & Reel |
| NSVM1MA152WKT1G | SC-59 (Pb-Free) | 3,000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

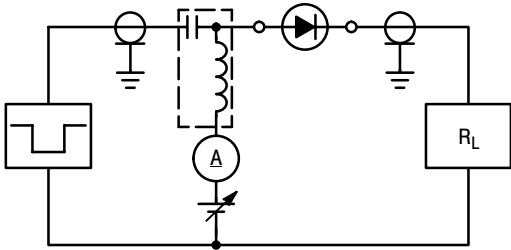
M1MA151WK, M1MA152WK

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

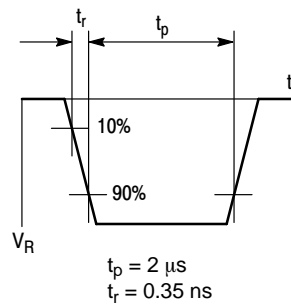
| Characteristic | Symbol | Condition | Min | Max | Unit |
|---|----------------------|--|----------|------------|------------------|
| Reverse Voltage Leakage Current M1MA151WK M1MA152WK | I_R | $V_R = 35\text{ V}$ $V_R = 75\text{ V}$ | – – | 0.1 0.1 | $\mu\text{A dc}$ |
| Forward Voltage | V_F | $I_F = 100\text{ mA}$ | – | 1.2 | Vdc |
| Reverse Breakdown Voltage M1MA151WK M1MA152WK | V_R | $I_R = 100\ \mu\text{A}$ | 40 80 | – – | Vdc |
| Diode Capacitance | C_D | $V_R = 0, f = 1.0\text{ MHz}$ | – | 2.0 | pF |
| Reverse Recovery Time (Figure 1) | t_{rr} (Note 2) | $I_F = 10\text{ mA}, V_R = 6.0\text{ V},$ $R_L = 100\ \Omega, I_{rr} = 0.1 I_R$ | – | 3.0 | ns |

2. t_{rr} Test Circuit

RECOVERY TIME EQUIVALENT TEST CIRCUIT



INPUT PULSE



OUTPUT PULSE

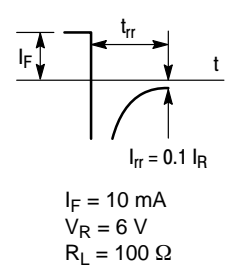


Figure 1. Reverse Recovery Time Equivalent Test Circuit

M1MA151WK, M1MA152WK

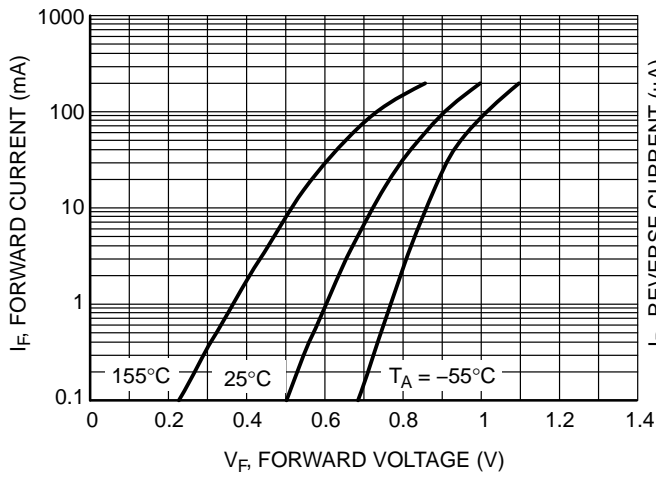


Figure 2. Forward Voltage

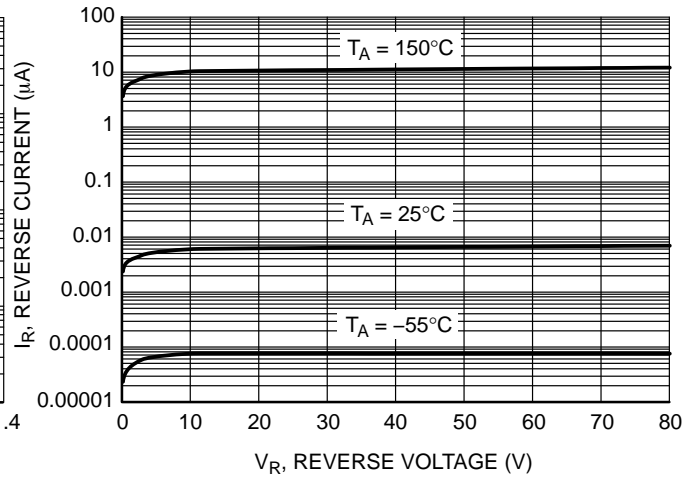


Figure 3. Reverse Leakage

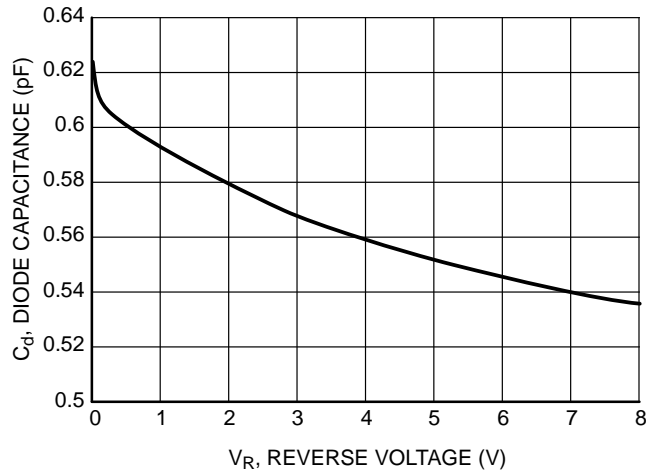


Figure 4. Diode Capacitance

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

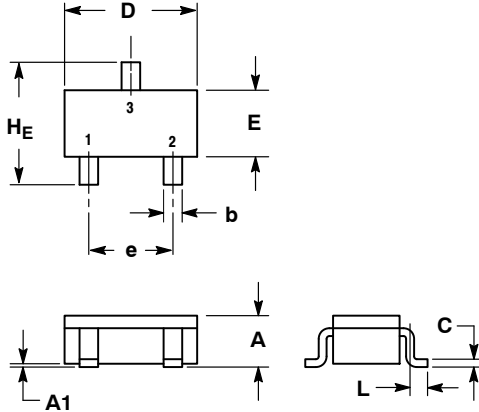
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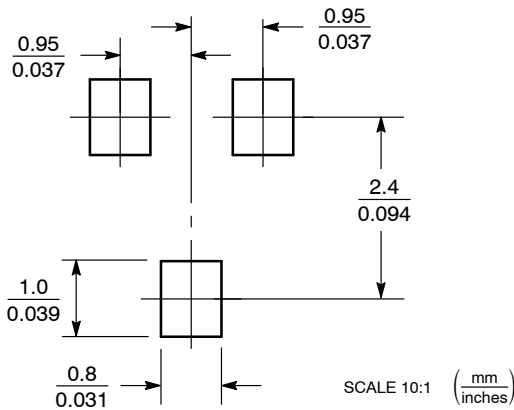
SC-59
CASE 318D-04
ISSUE H

DATE 28 JUN 2012

SCALE 2:1



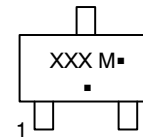
SOLDERING FOOTPRINT*



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

| DIM | MILLIMETERS | | | INCHES | | |
|-----|-------------|------|------|--------|-------|-------|
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 1.00 | 1.15 | 1.30 | 0.039 | 0.045 | 0.051 |
| A1 | 0.01 | 0.06 | 0.10 | 0.001 | 0.002 | 0.004 |
| b | 0.35 | 0.43 | 0.50 | 0.014 | 0.017 | 0.020 |
| c | 0.09 | 0.14 | 0.18 | 0.003 | 0.005 | 0.007 |
| D | 2.70 | 2.90 | 3.10 | 0.106 | 0.114 | 0.122 |
| E | 1.30 | 1.50 | 1.70 | 0.051 | 0.059 | 0.067 |
| e | 1.70 | 1.90 | 2.10 | 0.067 | 0.075 | 0.083 |
| L | 0.20 | 0.40 | 0.60 | 0.008 | 0.016 | 0.024 |
| HE | 2.50 | 2.80 | 3.00 | 0.099 | 0.110 | 0.118 |

GENERIC MARKING DIAGRAM



XXX = Specific Device Code
M = Date Code
▪ = Pb-Free Package*

(*Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

STYLE 1:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

STYLE 2:
PIN 1. ANODE
2. N.C.
3. CATHODE

STYLE 3:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 4:
PIN 1. CATHODE
2. N.C.
3. ANODE

STYLE 5:
PIN 1. CATHODE
2. CATHODE
3. ANODE

STYLE 6:
PIN 1. ANODE
2. CATHODE
3. ANODE/CATHODE

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

| | | |
|------------------|-------------|--|
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| DESCRIPTION: | SC-59 | PAGE 1 OF 1 |

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